

L6571

High voltage half bridge driver with oscillator

Features

- High voltage rail up to 600 V
- BCD off line technology
- 15.6 V Zener clamp on Vs
- Driver current capability:
 - Sink current = 270 mA
 - Source current = 170 mA
- Very low start up current: 150 mA
- Undervoltage lockout with hysteresis
- Programmable oscillator frequency
- Dead time 1.25 μs (L6571A) or 0.72 μs (L6571B)
- dV/dt immunity up to ±50 V/ns
- ESD protection

Description

The device is a high voltage half bridge driver with built in oscillator. The frequency of the oscillator

Figure 1. Block diagram



can be programmed using external resistor and capacitor.

The internal circuitry of the device allows it to be driven also by external logic signal.

The output drivers are designed to drive external nchannel power MOSFET and IGBT. The internal logic assures a dead time to avoid crossconduction of the power devices.

Two version are available: L6571A and L6571B. They differ in the internal dead time: 1.25 μs and 0.72 μs (typ.)



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1 Maximum ratings

1.1 Absolute maximum ratings

Table 1.Absolute maximum ratings

Symbol	Parameter	Value	Unit	
$I_{S}^{(1)}$	Supply current	25	mA	
V _{CF}	Oscillator resistor voltage	18	V	
V _{LVG}	Low side switch gate output	14.6	V	
V _{OUT}	High side switch source output	-1 to V _{BOOT} -18	V	
V _{HVG}	High side switch gate output -1 to V _{BOOT}			
V _{BOOT}	Floating supply voltage	618	V	
V _{BOOT/OUT}	Floating supply vs OUT voltage	18	V	
dV _{BOOT/dt}	VBOOT slew rate (Repetitive) ± 50		V/ns	
dV _{OUT/dt}	VOUT slew rate (Repetitive)	± 50	V/ns	
T _{stg}	Storage temperature	-40 to 150	°C	
TJ	Junction temperature -40 to 150			
T _{amb}	Ambient temperature (Operative)	-40 to 125	°C	

1. The device has an internal zener clamp between GND and VS (typical 15.6 V). Therefore the circuit should not be driven by a DC low impedance power source.

Note: ESD immunity for pins 6, 7 and 8 is guaranteed up to 900 V (human body model)

1.2 Thermal data

Table 2.Thermal data

Symbol	Parameter	MDIP8	SO8	Unit
R _{thJA}	Thermal resistance junction-ambient max	100	150	°C/W

1.3 Recommended operating conditions

Table 3. Recommended operating conditions

Symbol	Parameter		Max.	Unit
V _S	Supply voltage	10	VCL	V
V _{BOOT}	Floating supply voltage	-	500	V
V _{OUT}	High side switch source output	-1	VBOOT -VCL	V
f _{out}	Oscillation frequency		200	kHz



2 Pin connection





Table 4.Pin description

N°	Pin	Description				
1	VS	Supply input voltage with internal clamp [typ. 15.6V]				
2	RF	Dscillator timing resistor pin. A buffer set alternatively to VS and GND can provide current to the external resistor RF connected between pin 2 and 3. Alternatively, he signal on pin 2 can be used also to drive another IC (i.e. another L6569/71 to drive a full H-bridge)				
3	CF	Oscillator timing capacitor pin. A capacitor connected between this pin and GND fixes (together with RF) the oscillating frequency Alternatively an external logic signal can be applied to the pin to drive the IC.				
4	GND	Ground				
5	LVG	Low side driver output. The output stage can deliver 170mA source and 270mA sink [typ.values].				
6	OUT	Upper driver floating reference				
7	HVG	High side driver output. The output stage can deliver 170mA source and 270mA sink [typ.values].				
8	BOOT	Bootstrap voltage supply. It is the upper driver floating supply.				



3 Electrical data

 V_S = 12V; V_{BOOT} - V_{OUT} = 12V; T_j = 25 °C; unless otherwise specified.

Symbol	Pin	Parameter Test Condition		Min.	Тур.	Max.	Unit
V _{SUVP}	1	VS turn on threshold		8.3	9	9.7	V
V _{SUVN}		VS turn off threshold		7.3	8	8.7	V
V _{SUVH}		VS hysteresis		0.7	1	1.3	V
V _{CL}		VS clamping voltage	I _S = 5 mA	14.6	15.6	16.6	V
I _{SU}		Start up current	V _S < V _{SUVN}		150	250	μA
۱ _q		Quiescent current	$V_{\rm S} > V_{\rm SUVP}$		500	700	μA
I _{BOOTLK}	8	Leakage current BOOT pin vs GND	V _{BOOT} = 580V			5	μA
I _{OUTLK}	6	Leakage current OUT pin vs GND	V _{OUT} = 562V			5	μA
I _{HVG SO}	7	High side driver source current	V _{HVG} = 6V	110	175		mA
I _{HVG SI}		High side driver sink current	$V_{HVG} = 6V$	190	275		mA
I _{LVG SO}	5	Low side driver source current	$V_{LVG} = 6V$	110	175		mA
I _{LVG SI}		Low side driver sink current	$V_{LVG} = 6V$	190	275		mA
V _{RFON}	2	RF high level output voltage	I _{RF} =1mA	V _S -0.05		V _S -0.2	V
V _{RF OFF}		RF low level output voltage	I _{RF} = -1mA	50		200	mV
V _{CFU}	3	CF upper threshold		7.7	8	8.2	V
V _{CFL}		CF lower threshold		3.80	4	4.3	V
t _d		Internal dead time	L6571A L6571B	0.85 0.50	1.25 0.72	1.65 0.94	μS μS
DC		Duty cycle, ratio between dead Time + conduction time of high Side and low side drivers		0.45	0.5	0.55	
I _{AVE}	1	Average current from Vs	No Load, fs = 60KHz		1.2	1.5	mA
f _{out}	6	Oscillation frequency	RT = 12K; CT = 1nF	57	60	63	kHz

 Table 5.
 Electrical characteristcs



4 Oscillator frequency

The frequency of the internal oscillator can be programmed using external resistor and capacitor.

The nominal oscillator frequency can be calculated using the following equation:

Equation 1

$$f_{OSC} = \frac{1}{2 \cdot R_{F} \cdot C_{F} \cdot \ln 2} = \frac{1}{1.3863 \cdot R_{F} \cdot C_{F}}$$

Where R_F and C_F are the external resistor and capacitor.

The device can be driven in "shut down" condition keeping the C_F pin close to GND, but some cares have to be taken:

- 1. When CF is to GND the high side driver is off and the low side is on
- 2. The forced discharge of the oscillator capacitor C_F must not be shorter than 1us: a simple way to do this is to limit the current discharge with a resistive path imposing $R \cdot C_F > 1 \ \mu s$ (see fig.1)





Figure 4. Waveforms





D96IN417

Tr

Tf

4

5

6

Figure 5. Typical dead time vs. temperature dependency (L6571A)



time [nsec]

300

250

200

150

100

50

0

0



Figure 7. Typical frequency vs temperature dependency



For both high and low side buffers @25°C Tamb

2

3 C [nF]



Figure 9. Typical and theoretical oscillator frequency vs resistor value





5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.









Dim		mm.			inch	
DIM.	Min	Тур	Max	Min	Тур	Max
А	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D ⁽¹⁾	4.80		5.00	0.189		0.197
Е	3.80		4.00	0.15		0.157
е		1.27			0.050	
Н	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k			0° (min.),	8° (max.)		
ddd			0.10			0.004

Table 1. SO-8 mechanical data

1. Dimensions D does not include mold flash, protru-sions or gate burrs. Mold flash, potrusions or gate burrs shall not exceed 0.15mm (.006inch) in total (both side).

Figure 11. Package dimensions





6 Order information

Table 6.Ordering information

Order codes	Package	Packaging	
L6571A	DIP-8	Tubo	
L6571AD	<u>60</u> 8		
L6571AD013TR	L6571AD013TR 508		
L6571B	DIP-8	Tubo	
L6571BD	<u> </u>		
L6571BD013TR	300	Tape and reel	



7 Revision history

Table 7.Document revision history

Date	Revision	Changes
14-Jan-2004	5	No history because migration
15-Jan-2010	6	Updated Table 6 on page 10



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